

File Edit View Insert Tools Help

 BRS:19 2128 BRS:22 with 33 Pending Active

- L1:11 10/70270
- L2:14241 "SAMSUNG ELECTRO"
- L3:(1113288)1 (barrier conformal) near 2 (diffusion layer liner) antidiiffus.
- L4:(18514) (quantum ad) well MQW
- L5:(1113288)1 (barrier conformal) near 2 (diffusion layer liner) antidiiffus.
- L6:I01 "200076004"
- L7:I21 "200078004"
- L8:I32031 (257/14,17,98,101,103).OCLS.
- L9:(504314 with 6
- L10:(400546) diffusion
- L13:(56518 and 10
- L14:(40791) (MQW)
- L15:(881)14 with 6
- L16:(164)15 and 9
- L8:I21 "6657234".pn.
- L12:(108110 with 11
- L17:(11170495) (dop\$4 impurit\$9 (ion near3 implant\$3) diffus\$4)
- L18:(901110 with 17
- L19:(302118 and 14
- L20:(733051) (dop\$4 impurit\$9 (ion near3 implant\$3))
- L21:(59112 same 20

Log: 12/20/2005 07:45:00 Date: 11/04/1000

Search: 12 same 20

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Printed on 11/04/2005

April 2005

U	I	Inventor / Document Issu	P:	Title	Current	Current I	Retrie	S	O	P:	Image	DoP
1		Kim, Sun W	US 200500	2005 12 Nitride-based semiconductor device	257/14			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 20050
2		Flynn, Jeff	US 200402	2004110 III-nitride optoelectronic device struct	257/94			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 20040
3		Vasuda, Tak	US 2004018	2004 14 Light-emitting device, method of fabric	313/49			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 200401
4		Chang, Ying	US 2004016	2004 16 Method and apparatus for improving w	372/45			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 200401
5		Kurayagure, K	US 2004012	2004 14 Gallium nitride compound semiconduc	257/34 257/101			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 200401
6		Bow, David	US 200400	2004 15 Group III-V semiconductor devices incl	257/11 257/14			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 20040
7		Kozaki, Tok	US 200302	2003 3 Nitride semiconductor device	257/20 257/E33.0			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 20030
8		Massa, Joh	US 200302	2003 13 Semiconductor substrates and structu	257/94 257/E21.2			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 20030
9		Hirata, Koichi	US 200301	2003 2 Semiconductor light emitting element	257/99 257/E33.0			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 200301
10		Tada, Hitos	US 200301	2003 19 Semiconductor light modulator	359/24			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 200301
11		Tsuchiya, T	US 200300	2003 18 Optical semiconductor devices and fab	257/14 257/492			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>		US 200300

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